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KIRIRI WOMENS' UNIVERSITY OF SCIENCE AND TECHNOLOGY
UNIVERSITY EXAMINATION, 2019/2020 ACADEMIC YEAR
SECOND YEAR, FIRST SEMESTER EXAMINATION
BACHELOR OF SCIENCE IN COMPUTER SCIENCE

KCS 203 - ELECTRONICS

Date: 8th April, 2019
Time: 2.30pm – 4.30pm

INSTRUCTIONS TO CANDIDATES

ANSWER QUESTION ONE (COMPULSORY) AND ANY OTHER TWO QUESTIONS

QUESTION ONE (30 MARKS)

- a) Briefly describe the mechanism of electric conduction in:
- Metals
 - Conducting Liquids
 - Vacuum
- (9 Marks)
- b) Describe the formation of the P –type extrinsic semiconductor material, using a clearly labeled diagram.
- (4 Marks)
- c) A 6.0V stabilized power supply is required to be produced from a 24V DC power supply input source. The maximum power rating $P_{Z_{max}}$ of the Zener diode is 0.5W. Using the Zener regulator circuit Figure Q1c. (Assume diode resistance $R_D = 0\Omega$) calculate;
- The total supply current I_S at full load.
 - The diode current I_Z , if a load resistor of $5k\Omega$ is connected across the Zener diode.
 - The minimum value of the series resistor, R_S

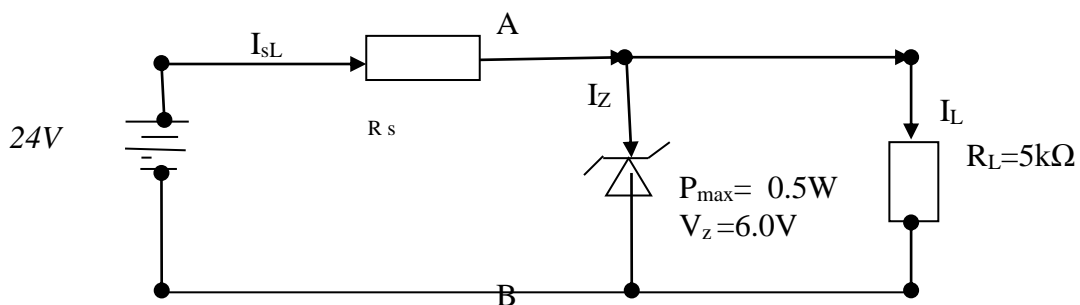


Figure Q1c.

(9 Marks)

- d) Using both, a labeled block diagram, and a circuit diagram, describe the following configurations of a properly biased PNP bipolar junction transistor:
- Common Base
 - Common Emitter

(8 Marks)

QUESTION TWO (20 MARKS)

- a) An instantaneous current, $i = 600 \sin \omega t$ mA flows through a pure resistance of $5 \text{ k}\Omega$. Find the current value flowing and power dissipated in the resistor when $\omega t = 0.75\pi$ rad. (10 Marks)
- b) A transistor has $\alpha_{dc} = 0.85$. Calculate β_{dc} . (6 Marks)
- c) A transistor has the following currents: $I_B = 40 \text{ mA}$ and $I_C = 5 \text{ A}$. Calculate I_E . (4 Marks)

QUESTION THREE (20 MARKS)

- a) Explain with the aid of a labeled diagram the use of a zener diode in a regulated dc power supply. (12 Marks)
- b) Describe the formation of the P-N junction depletion layer, using a clearly labeled diagram. (8 Marks)

QUESTION FOUR (20 MARKS)

- a) i) What is an operational amplifier (Op Amp)? (4 Marks)
- ii) State FOUR ideal characteristics of an Op Amp (4 Marks)
- b) In the non-inverting OP-AMP, Figure Q4, if $R_1 = 1.5 \text{ k}\Omega$, $R_f = 15 \text{ k}\Omega$, calculate:
- Voltage gain
 - Output voltage if $V_{in} = 100 \text{ mV}$

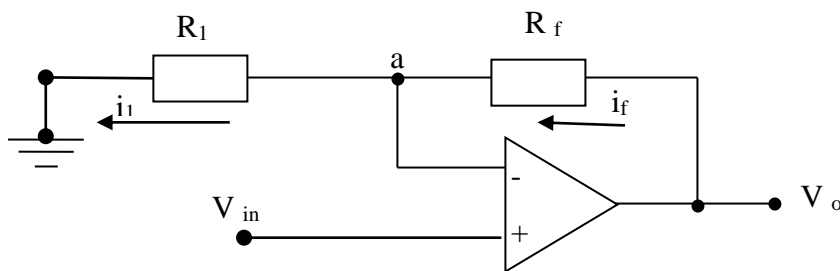


Figure Q 4

(12 Marks)

QUESTION FIVE (20 MARKS)

- a) In Fig.Q5a, Calculate the drain current, I_D , for the following values of V_{GS} (assume $V_{DS} \geq V_{DS(P)}$):
- 0V,
 - 0.5V,
 - 1V

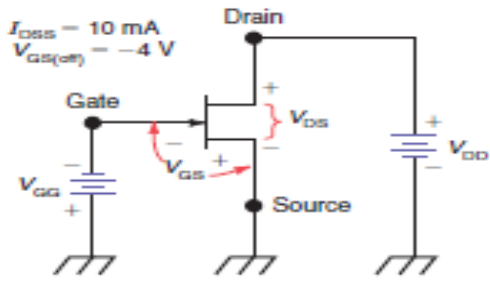


Fig.Q5a

(12 Marks)

- b) Describe and show on same figure how the following breakdown mechanisms occur in $p-n$ junctions:
- i) Zener Effect.
 - ii) Avalanche Effect.

(8 Marks)